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All SiC Grid-Connected PV Supply with HF Link MPPT Converter: System Design Methodology and Development of a 20 kHz, 25 kVA Prototype

Serkan Öztürk ¹, Mehmet Canver ², Işık Çadırcı ¹ and Muammer Ermiş ²,*

- Department of Electrical and Electronics Engineering, Hacettepe University, Beytepe, Ankara 06800, Turkey; ozturk@ee.hacettepe.edu.tr (S.Ö.); cadirci@ee.hacettepe.edu.tr (I.Ç.)
- Department of Electrical and Electronics Engineering, Middle East Technical University, Ankara 06800, Turkey; mehmet.canver@artielektronik.com.tr
- * Correspondence: ermis@metu.edu.tr; Tel.: +90-312-210-2364

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Abstract: Design methodology and implementation of an all SiC power semiconductor-based, grid-connected multi-string photovoltaic (PV) supply with an isolated high frequency (HF) link maximum power point tracker (MPPT) have been described. This system configuration makes possible the use of a simple and reliable two-level voltage source inverter (VSI) topology for grid connection, owing to the galvanic isolation provided by the HF transformer. This topology provides a viable alternative to the commonly used non-isolated PV supplies equipped with Si-based boost MPPT converters cascaded with relatively more complex inverter topologies, at competitive efficiency figures and a higher power density. A 20 kHz, 25 kVA prototype system was designed based on the dynamic model of the multi-string PV panels obtained from field tests. Design parameters such as input DC link capacitance, switching frequencies of MPPT converter and voltage source inverter, size and performance of HF transformer with nanocrystalline core, DC link voltage, and LCL filter of the VSI were optimized in view of the site dependent parameters such as the variation ranges of solar insolation, module surface temperature, and grid voltage. A modified synchronous reference frame control was implemented in the VSI by applying the grid voltage feedforward to the reference voltages in abc axes directly, so that zero-sequence components of grid voltages are taken into account in the case of an unbalanced grid. The system was implemented and the proposed design methodology verified satisfactorily in the field on a roof-mounted 23.7 kW multi-string PV system.

Keywords: dynamic PV model; grid-connected VSI; HF-link MPPT converter; nanocrystalline core; SiC PV Supply

1. Introduction

Various grid-connected photovoltaic system concepts and topologies have been summarized previously [1–4]: (i) micro inverters [5,6]; (ii) residential systems supplied from a PV string [7,8]; (iii) commercial/residential systems supplied from multiple PV strings having their own maximum power point tracking (MPPT) converters and a central inverter [9,10]; and (iv) commercial/utility-scale PV plants supplied from a common DC link with a central inverter [11]. The central inverter in [11] performs direct conversion of PV power to AC from multiple PV strings. MPPT and reliable and efficient conversion of PV power to AC at grid frequency are the major design issues for two stage grid-connected PV systems [12]. In the PV systems performing direct conversion of PV power to AC, the voltage of the common DC link is varied by the central inverter against the changes in solar insolation and panel temperature [13]. An MPPT algorithm integrated into a two-layer controller is

recommended in [14] for direct conversion of PV power through a three-phase grid-connected VSI. A neural network based MPPT algorithm is proposed in [15] to improve the dynamic performance of DC capacitor voltage at the input of VSI and to maintain faster tracking response against sudden changes in solar irradiance. Grid-connected PV supplies can be classified into two groups: (i) those having transformerless inverter topologies [16]; and (ii) those having magnetic transformers usually on the grid side [17]. Transformerless PV supplies require more complex and expensive inverter topologies as compared to PV supplies having transformers for galvanic isolation to prevent the flow of common-mode currents [18–22].

In the vast majority of commercially available PV supplies, new generation hybrid IGBTs are currently employed to synthesize grid frequency voltages and/or currents. In the next generation PV inverters, simpler circuit designs such as two-level instead of multi-level inverters are expected to be used for fewer components and hence higher reliability [23]. Wide bandgap (WBG) devices such as SiC power MOSFETs will be employed for higher switching frequency to reduce the size of passive components, heatsinks and hence the volume of the PV supply, as foreseen in [23]. WBG semiconductors show superior material properties, enabling potential power device operation at higher temperatures, voltages, and switching speeds than current Si technology [24].

In recent years, performances of all SiC PV supplies consisting of DC/DC converters and three-phase grid-connected inverters are assessed, as reported in [25–27]. These use either three-level T-type inverter topology [26] or cascaded multi-level inverter topology [27]. All SiC inverters such as single-phase H-bridge converter [28], neutral point clamped (NPC) T-type three-phase inverter [29], and three-phase five-level T-type inverter [30] are used to perform direct conversion of PV power to the grid. Design and performances of some non-application-specific two-level three-phase SiC inverters are presented in [31–34].

Since the power converters in PV supplies are presently switched at relatively higher frequencies, ranging from a few kHz to a few tens of kHz, sizing and design of these converters require the dynamic model of the PV cells, modules or arrays instead of the well-known static model. Some attempts have been made to obtain dynamic model parameters of various types of PV cells or modules by theoretical calculations and/or measurements [35–40]. The use of internal solar cell diffusion capacitance to replace the input capacitor in boost derived DC-DC converters has been proposed in [41] for energy harvesting applications. In almost all of the two-stage PV supplies, boost type DC-DC converters have been used for MPPT. Recently, in this area, small size SiC MOSFET [42–45] and SiC JFET based [46] MPPT converters are reported in the literature. A 1-MW solar power inverter with boost converter using all SiC power modules has been presented in [47]. A 3.5 kW, 100 kHz all SiC buck/boost interleaved MPPT converter is proposed in [48] for higher conversion efficiency. Design, construction, and testing of a general purpose 750-V, 100-kW, 20-kHz bidirectional dual active bridge DC-DC converter using all SiC dual modules with HF transformer is described in [49] to provide maximum conversion efficiency from the DC-input to the DC-output terminals.

Design of the AC filter on the grid side of a VSI is a compromise between performance and size. A step-by-step design procedure of an LCL filter for a grid-connected three-phase PWM voltage source converter is proposed in [50]. A new design method is recommended in [51] for LCL and LLCL filters with passive damping to be used in single-phase grid-connected VSIs. Peña-Alzola et al. [52] examined passive damping losses in LCL filters. Design methodology, analysis and performance of LCL filters for three-phase grid-connected inverters are also described in [53,54]. Stability regions of active damping control for LCL filters are discussed in [55]. A generalized LCL filter design algorithm for grid-connected VSIs is presented in [56].

The common control methods for three-phase grid-connected inverters are: (i) synchronous reference frame control (in dq-axes) [57–59]; (ii) stationary reference frame control (in $\alpha\beta$ -axes) [60]; and (iii) natural reference frame control (in abc-axes) [61]. The main drawback of the synchronous reference frame control is the poor compensation capability of the low-order harmonics in the case of PI based controllers [60]. To cope with this drawback, the control system can be equipped with

proportional resonant harmonic compensators, one pair for each prominent low order sidekick harmonics produced by the system itself [62]. In stationary reference frame control method, two proportional resonant controllers can be used in $\alpha\beta$ -axes for the fundamental component to eliminate possible steady-state error which may arise in PI control. However, the number of PR controllers for low-order harmonic compensation are doubled. In *abc* control strategy, an individual controller is required for each line current on the grid side. In this control method, all types of controllers such as PI controller, PR controller, hysteresis controller, dead-beat controller and repetitive controller can be adopted [61].

This paper recommends a grid-connected, all SiC Power MOSFET based multi-string PV supply with a HF link MPPT converter in each string and a two-level central inverter. The design methodology described in the paper utilizes a custom dynamic model of the roof-mounted multi-string PV system, and site dependent parameters. These parameters are variation ranges of solar insolation, module surface temperature, and grid voltage. In the design procedure the following are optimized: (i) input DC link capacitance; (ii) switching frequencies of MPPT converter and VSI; (iii) the size and performance of HF transformer with nanocrystalline core; (iv) the DC link voltage; and (v) the LCL filter of VSI. Corresponding field test results of the implemented 20 kHz, 25 kVA prototype are presented. It has been shown that the HF link converter in cascade with a two-level VSI provides a viable alternative to multi-string PV supplies with a competitive efficiency, lower harmonic distortion and a much higher power density. This PV supply topology with a HF link MPPT converter makes possible the use of a simple and reliable, two-level, voltage source PV inverter for grid connection. In the case of PV supplies with non-isolated MPPT converters or those performing direct conversion of PV power to the grid, either complex inverter topologies or bulky grid-side common-mode filters or coupling transformers would be required to minimize the flow of undesirable common-mode currents.

2. System Description

2.1. General

Block diagram representation of all SiC grid-connected PV supply with HF link is as shown in Figure 1a. With the advents in SiC power MOSFETs, the kVA rating of three-phase, two-level voltage source all SiC central inverter can reach 175–400 kVA, by employing commercially available three half-bridge all SiC modules in Table 1 (by February 2018) for direct connection to 400 V l-to-l, 50 Hz utility grid. Each MPPT converter with DC/AC/DC link can be designed to process 15–25 kW PV power by employing SiC half-bridge modules, TO-package SiC Schottky diodes, and a nanocrystalline transformer core. The MPPT converter rating in the application described in this paper is limited to 25 kW by considering the partial shading risk of multi-string PV panels. In the experimental system, five mono-crystalline PV strings of 23.7 kW peak under standard test conditions, with adjustable tilt angles occupy nearly 375 m² in the roof area as shown in Figure 2. In this study, the experimental work was carried out on the prototype system given in Figure 1b.

Table 1. Commercially available all SiC power MOSFET half-bridge modules that can be employed in central inverter in Figure 1a/by February 2018.

Manufacturer	Half-Bridge Module	V_{DS} , V	I_D , A
ROHM [63]	BSM300D12P2E001	1200	300
CREE [64]	CAS325M12HM2	1200	325
SEMIKRON [65]	SKM500MB120SC	1200	541
Mitsubishi [66]	FMF800DX-24A	1200	800

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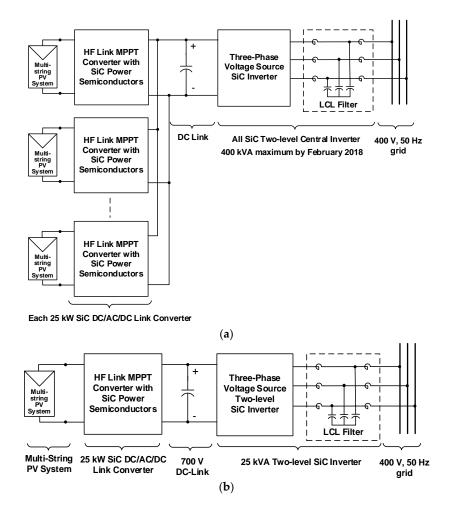


Figure 1. All SiC three-phase grid-connected PV supply with high-frequency link: (a) Multi-string PV inverter system; and (b) Experimental set-up.



Figure 2. Roof-mounted 23.7 kW at 1000 W/m² and 25 °C multi-string PV system containing 95 CSUN250-72M modules (five parallel connected strings of 19 series modules; with adjustable tilt angles of 15° , 30° , 45° and 60°); coordinates 39.890917, 32.782278; five modules in the photograph are idle; terminal box of the system inside the laboratory is shown at the right bottom corner of photograph while the pyranometer is at left bottom corner.

Advantages and disadvantages of the multi-string PV supply system in Figure 1a can be summarized as follows:

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(i) In medium power applications, as a wide bandgap device, SiC power MOSFETs can be switched at higher frequencies (a few tens of kHz) in comparison with Si IGBTs. This ability brings us the following benefits:

- Higher efficiency at the same switching frequency;
- Much smaller HF transformer in DC/AC/DC link of the MPPT converter;
- Much smaller electrolytic or metal film DC link capacitor at the output of the MPPT converter;
- Much smaller distributed metal film DC link capacitor bank in the laminated bus/PCB of the inverter circuit;
- Smaller LCL filter bank at the output of the PV inverter;
- Silent operation;
- Permits the use of two-level three-phase bridge inverter topology to conform with the power quality regulations on the grid side; and
- Extends the range of high order current harmonics that can be eliminated.
- (ii) They eliminate the need for a bulky, grid-side PV transformer to provide electrical isolation.
- (iii) Separation of installed PV panels into multiple strings having MPPT converters minimizes the undesirable effects of partial shading.
- (iv) The central inverter has higher efficiency and lower cost in comparison with the usage of several smaller scale inverters.
- (v) In most countries, the PV system in Figure 1a can be directly connected to the low-voltage (LV) side of distribution transformers without the permission of distribution system operators. Although standard power ratings for distribution transformers are 100, 250, 400, and 630 kVA [67], higher ratings up to 2 MVA are also in service.
- (vi) Since the HF link MPPT converter is cascaded with the grid-connected PV inverter, overall efficiency is 1–2% lower than that of PV converters performing direct conversion of PV power to the grid. However, the PV systems having non-isolated MPPT converters or performing direct conversion of PV power to the grid should have more complex converter topologies to minimize common-mode currents.

2.2. MPPT Converter with HF Link

A prototype of the MPPT converter with HF link shown in Figure 1b is designed and implemented. MPPT converter is composed of a SiC Power MOSFET based single-phase H-bridge converter, a HF transformer, and a SiC Schottky diode rectifier. The circuit diagram of the power stage, the control circuitry, and top and side views of the implemented MPPT converter prototype are as shown in Figure 3.

2.3. Three-Phase Two-Level Voltage Source Inverter

A prototype of the three-phase two-level voltage source inverter shown in Figure 1b was designed and implemented. This converter topology was chosen for the following reasons:

- The ability of SiC power MOSFETs at high switching frequencies for lower harmonic current content;
- Minimum power semiconductor count gives higher reliability in comparison with multi-level converters;
- Common-mode current is not a design concern because of the HF transformer in the MPPT converter; and
- PV inverter delivers power to one of the most common low voltage utility grid.

The circuit diagram of the power stage and its control circuitry, and top and side views of the implemented inverter prototype are shown in Figure 4.

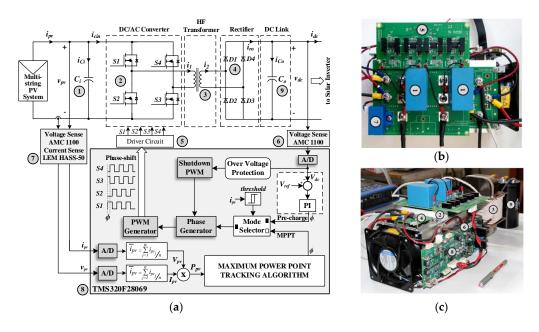


Figure 3. All SiC MPPT converter with high-frequency link: (a) power stage and its control circuitry; (b) yop view of the developed hardware; and (c) side view. (1) Metal Film 30//30 μF Input Capacitor Bank (EPCOS B32778G0306K); (2) All-SiC Half Bridge Module (CREE CAS120M12BM2); (3) Nanocrystalline Core (SU-102b) Based HF Transformer; (4) SiC Schottky Diode (CREE C4D40120D); (5) Dual Channel SiC MOSFET Driver (CREE CGD15HB62P); (6) Fully-Differential Isolation Amplifier (TI AMC-1100); (7) Hall-Effect Current Transducer (LEM HASS 50-S); (8) Microcontroller (TI TMS320F28069); (9) Electrolytic 3400 μF Output Capacitors (EPCOS B43456-A9688-M).

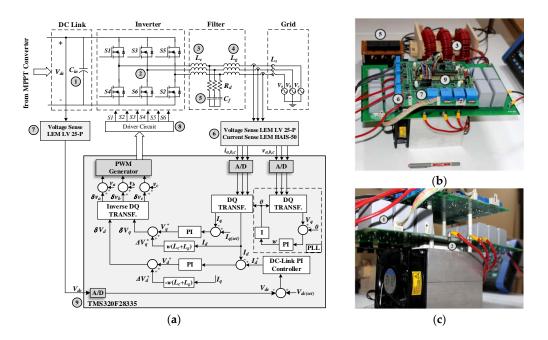


Figure 4. All SiC three-phase grid-connected two-level inverter: (a) power stage and its control circuitry; (b) top view of the developed hardware; and (c) side view. (1) Metal Film 12 × 40 μF Input Capacitor Bank (VISHAY MKP1848640094Y); (2) All-SiC Six-Pack Three-Phase Module (CREE CCS050M12CM2); (3,4) X-Flux L_c = 250 μH and L_g = 50 μH Filter Inductor (Magnetics 0078337A7); (5) Metal Film 15 μF Filter Capacitor (VISHAY MKP1848S61510JY5F); (6) Hall-Effect Current Transducer (LEM HAIS 50-P); (7) Voltage Transducer (LEM LV25-P); (8) Single Channel SiC MOSFET Driver (CREE CRD-001); (9) Experimenter Kit (TI TMDSDOCK28335).

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3. Modeling and System Design

The recommended modeling and system design methodology is described in this section for the existing multi-string PV system shown in Figure 2. For another multi-string PV system configuration, the same design principles can be applied.

3.1. Dynamic Model of Multi-String PV System

Even in the steady-state operation of PV supplies, their power converters such as the MPPT converter and the inverter operate in the periodic transient state, instead of pure DC operation. Therefore, in the analysis and design of such systems, a proper dynamic model of the multi-string PV system is to be used. Several attempts have been made to obtain dynamic models of a PV module [35–41]. However, in this research work, the dynamic model parameters of the roof-mounted multi-string PV system shown in Figure 2 were obtained from a set of experimental data. It includes also all cabling and wirings up to the input terminals of the MPPT converter. These parameters were then combined with the static model of the CSUN250-72M modules available in MATLAB/Simscape/Power Systems R2016b for use in the design work.

Equivalent circuits of the multi-string PV system in Figure 2 consisting of 95 pieces of CSUN250-72M modules (5 \times 19 modules) are as shown in Figure 5. Static model in Figure 5a is determined for the PV array in Figure 2 by using the PV array block developed by the National Renewable Energy Laboratory (NREL) System Advisor Model and available in MATLAB/Simscape/Power Systems R2016b. However, the design of the PV supply presented in this paper is based on the dynamic model of the PV system shown in Figure 5b.

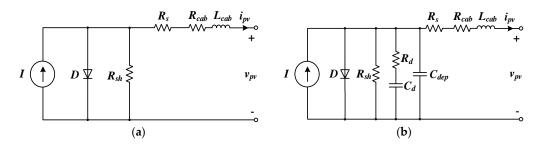


Figure 5. Equivalent circuit of the multi-string PV system in Figure 2 consisting of 95 pieces of CSUN250-72M modules (5 × 19 modules). (a) Static model: R_{sh} = 490 Ω and R_s = 1.33 Ω are, respectively, the equivalent shunt and series resistances calculated by MATLAB/Simscape/Power Systems; and R_{cab} =10 mΩ and L_{cab} = 45 μH are the equivalent parameters of all cabling and wiring and estimated from experimental results given in Figure 6. (b) Dynamic model: C_d = 4 μF is the equivalent diffusion capacitance and R_d = 3 Ω is its series resistance, and C_{dep} = 600 nF is the equivalent depletion layer capacitance, which were estimated from experimental results given in Figure 6.

The topology of this dynamic model is nearly the same as the one given in [41]. The dynamic model parameters are estimated from the results of two tests conducted on the multi-string PV system. In the first test, multi-string PV system is solidly short-circuited at the terminal box and the short-circuit current is recorded as shown in Figure 6a. In the second test, a slightly inductive resistive bank is suddenly connected to the open-circuited multi-string PV system terminals and the terminal voltage and the current are recorded as shown in Figure 6b. Parameters of the multi-string PV system estimated from the current and voltage records shown in Figure 6 are as given in the caption of Figure 5.

These experimental records are compared with the simulation results obtained by MATLAB/Simscape/Power Systems, for the static and dynamic models separately under the same test conditions, as given in Figure 6. It is clear from this figure that the dynamic model gives much better results than those of the static model, and it can therefore be satisfactorily used in the design of HF link MPPT converter.

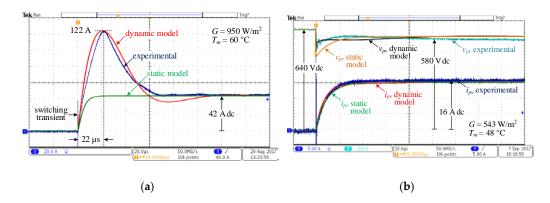


Figure 6. Transient response of the multi-string PV system at the input of the MPPT converter (Experimental: Tektronix MSO3034 oscilloscope, Tektronix TCPA300 current probe amplifier, Tektronix TCP404XL current probe; static model as given in Figure 5a; dynamic model as given in Figure 5b; Pyranometer EKO MS-410; Fluke Ti29 infrared camera): (**a**) from open-circuit to short-circuit; and (**b**) from open-circuit to partial resistive load ($R_L = 42.5 \Omega$, $L_L = 278 \mu$ H measured by GW INSTEK LCR-817 LCR meter at the resistor temperature of 72 °C).

3.2. Three-Phase Two-Level VSI

In this subsection, optimum DC link voltage and switching frequency are determined and the design of the inverter circuit, its control circuitry and LCL filter are described. The design of the HF link converter is directly affected by the optimum DC link voltage determined in this subsection.

3.2.1. Optimum DC Link Voltage

DC link voltage, V_{dc} , is kept constant by the inverter against the variations in PV power over the entire operating range of the PV supply. At the optimum value of V_{dc} , modulation index, M in Equation (1) of the inverter circuitry should vary in a range as close as possible to unity in order to minimize harmonic distortion of the output line currents.

$$M = (2\sqrt{2}/\sqrt{3})(V/V_{dc}) \tag{1}$$

where V is the l-to-l value of either grid voltage, V_s or consumers load voltage, V_t . Furthermore, in calculating the variation range of M, permissible changes in 400 V l-to-l, 50 Hz grid voltage are as specified in IEC 60038 2002-07 Standard Voltages [68]. This standard specifies the maximum changes in grid voltage, V_s as +6% to -0% while a further ± 4 % at the consumers load voltage, V_t . In view of these considerations, the variation ranges of M are calculated and plotted (Figure 7).

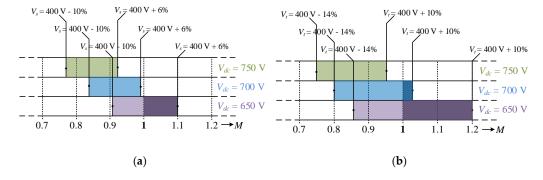


Figure 7. The variation range of modulation index, M as a function of chosen DC link voltage, V_{dc} and operating voltage (acceptable low voltage variation ranges for 230/400 V, 50 Hz systems are as specified in IEC 60038 2002-07 Standard Voltages): (a) for the supply side voltage range of $V_s = 400 \text{ V} + 6\%$ to -10%; and (b) for the utilization voltage range of $V_t = 400 \text{ V} + 10\%$ to -14%.

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As can be understood from the results in Figure 7, the optimum value of V_{dc} is around 700 V. This choice may result in operation slightly in over-modulation region as given in Figure 7b. Since inverter rating is 25 kVA/22.3 kW for the available multi-string PV system, the inverter can deliver nearly 11 kVAr inductive or more to bring V_t back to $V_s = 400 \text{ V} + 6\%$. Application of third harmonic injection method [69,70] might be an alternative design approach in which the optimum value of V_{dc} is to be nearly 600 V for $V_s = 400 \text{ V} + 6\%$.

3.2.2. Optimum Switching Frequency

Higher switching frequencies for the two-level three-phase inverter with different modulation techniques such as SPWM, SVPWM, etc., excluding SHEM, result in low harmonic distortion for the line currents injected into the grid [71]. In this research work, sinusoidal PWM is chosen as the modulation technique because of its simplicity, and its ability to illustrate basic design guidelines. Since SiC Power MOSFETs can be switched at higher frequencies in comparison with Si IGBTs for the same power dissipation and solar inverter rating, power loss components of solar inverter with SPWM modulation are calculated for a reasonable operating frequency range, e.g., at $f_{sw} = 10$, 20, and 30 kHz, by using the expressions and manufacturers' design tools given in [72].

The associated pie-charts are shown in Figure 8. All wiring and cabling losses between discrete components, inverter, LCL filter, and grid are ignored in the preparation of Figure 8. In addition, extra power losses due to the switching ripple current through the power MOSFETs are not considered by the power loss calculation tools mentioned above in the calculation of conduction and switching losses. In summary, slightly higher loss content and a lower efficiency are expected for the solar inverter in the field tests.

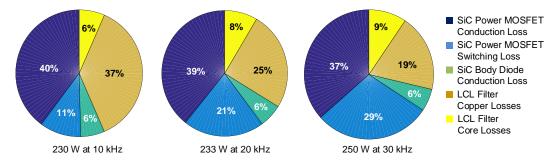


Figure 8. Power loss components of solar inverter for different switching frequencies at $P_o = 22.3$ kW. Numerical values are rounded.

In the design of LCL filter at different switching frequencies, only the converter side inductance, L_c , is optimized to keep its peak-to-peak current ripple constant at 25%. Power loss components in the associated LCL filters are then used in the preparation of pie charts in Figure 8. Although 10 kHz switching frequency reduces the power dissipation marginally in comparison with that of the 20 kHz, a considerably larger LCL filter size is to be used. Therefore, in the design and implementation of the solar inverter, $f_{sw} = 20$ kHz is chosen, which is a compromise between losses and LCL filter size.

3.2.3. LCL Filter Design

An LCL filter consisting of inverter side inductors L_c , shunt capacitors C_f , passive damping resistors R_d , and grid side inductors L_g are considered in design, as shown in Figure 4a. The LCL filter should be designed to have not more than 10 A peak-to-peak ripple superimposed on 36 A rms fundamental current in L_c at 25 kVA, and 400 V l-to-l. Peak-to-peak ripple remains nearly constant over the entire operating range of the all SiC three-phase grid-connected two-level inverter and is 25% at 25 kVA, 400 V l-to-l. The corner frequency of the LCL filter is chosen around 1/3rd of the 20 kHz switching frequency. These choices are consistent with the recommendations given in various

papers [50–56]. The transfer function Bode plots of undamped LCL filter for three different L_c , C_f , and L_g parameter sets are given in Figure 9a. All of them provide nearly 100 dB attenuation at switching frequency. Among these, $L_c = 250~\mu\text{H}$, $C_f = 15~\mu\text{F}$, and $L_g = 50~\mu\text{H}$ parameter set is chosen for the implementation. Red colored parameter set ($L_c = 350~\mu\text{H}$, $C_f = 20~\mu\text{F}$, $L_g = 50~\mu\text{H}$) is not chosen because its L_c is nearly 40% greater than that of the optimum design and provides unnecessarily high attenuation. Although the green colored parameter set ($L_c = 150~\mu\text{H}$, $C_f = 10~\mu\text{F}$, and $L_g = 50~\mu\text{H}$) gives minimum LCL size, it is also not chosen in the implementation because it makes narrower the control range of the phase shift angle, and hence may cause undesirable oscillations in the output power and possible instability. On the other hand, field experience has shown that larger LCL filter size reduces harmonic content of the line currents and maintains stability of the inverter.

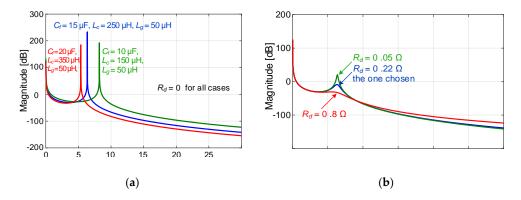


Figure 9. Transfer characteristics of various LCL filters shown in: (a) undamped filters, R_d = 0; and (b) effects of R_d on the transfer characteristic on the chosen LCL filter (L_c = 250 μH, C_f = 15 μF, and L_g = 50 μH).

Very high amplification of the current component at resonance frequency can be entirely eliminated by either passive or active damping technique. In this research work, passive damping is preferred and the damping resistance R_d is connected in series with C_f . In choosing the optimum value of R_d , a compromise is needed between copper losses and damping effect.

The effects of various damping resistors on the current transfer function bode plots of the chosen parameter set are as given in Figure 9b. Although lower R_d values are less dissipative, their damping effect is inadequate. On the other hand, higher R_d values provide strong damping at resonance frequency at the expense of higher losses and reduced attenuation at high frequencies. R_d = 0.22 Ω is therefore chosen for the implementation.

3.2.4. Controller Design

In this paper, active power delivered to the grid is controlled by using the rotating reference frame synchronized with the grid frequency by implementing a modified version of the control technique presented in [50]. The block diagram of the designed and implemented DSP (TMS320F28335) based controller is shown in Figure 4a. Line to neutral voltages $v_{a,b,c}$ and line currents $i_{a,b,c}$ on the grid side, and DC link voltage V_{dc} are the inputs to the controller. These quantities are sampled at 10 kHz/channel. Set values of the DC link voltage, $V_{dc(set)}$ and $I_{q(set)}$ are adjusted, respectively, to 700 V and 0 A in the control software. PWM signals applied to the driver circuits are the outputs of the control system. Control actions are achieved firstly in rotating DQ reference frame which is synchronized with the grid frequency by the PLL circuit, and then in ABC reference frame.

To be able to lock to the grid, reference value of V_q should be 0. PI controller in the PLL circuit calculates synchronous speed, ω which is equal to angular frequency of the grid voltage. ω is then integrated to give space angle θ , where θ defines relative position of synchronously rotating reference frame with respect to the stationary ABC reference frame, i.e., relative position of rotating d-axis with

respect to stationary a-axis. I_q is compared with $I_{q(set)} = 0$ for zero reactive power and then processed in the PI controller to generate reference signal V_q^* . Cross-coupling term ΔV_q^* is then superimposed on V_q^* to compensate for potential drop on the total filter inductance and also for better transient response in the feed-forward form of cross-coupling terms. Actual value of DC link voltage V_{dc} is compared with its set value $V_{dc(set)}$ and resulting error signal is then processed in a PI controller to generate reference signal I_d^* . I_d^* is then compared with actual current I_d and processed in a PI controller to generate reference value, V_d^* . Cross-coupling term ΔV_d^* is superimposed on V_d^* to compensate for potential drop on the total filter inductance and also for better transient response.

The above operations yield main control signals δV_d and δV_q in synchronously rotating reference frame. Instead of superimposing δV_d and δV_q on d- and q-axis components, V_d and V_q of the grid voltages, δV_d and δV_q are transformed back to abc-axes, resulting in δ_{va} , δ_{vb} , and δ_{vc} , and these control signals are then superimposed on the actual grid voltage waveforms v_a , v_b , and v_c . This modification results in lower harmonic distortion in the line current waveforms because when the actual grid voltages are transformed to dq reference frame (instead of dq0) and then used in the control together with δV_d and δV_q , odd multiples of third harmonic (zero sequence component) would not be taken into account.

3.3. MPPT Converter with HF Link

In this subsection, switching frequency of the H-bridge converter and the transformer turns-ratio are optimized in view of the following design constraints:

- (i) Multi-string PV system and its dynamic model should be known. For this purpose, the system in Figure 2 and its dynamic model in Figure 5b are prespecified for the experimental set-up in Figure 1b.
- (ii) The variation range of global solar insolation, G, should be known for the geographical location at which the PV system is going to be installed, i.e., $G \le 1000 \text{ W/m}^2$ for the experimental set-up.
- (iii) The variation range of module surface temperature, T_m , should be estimated, i.e., $10 \le T_m \le 70$ °C for the experimental set-up.
- (iv) DC link voltage, V_{dc} , is kept constant at 700 V by the solar inverter in the experimental set-up.
- (v) DC link capacitance, C_0 in Figure 3a is taken to be 3400 μ F.

All calculations are carried out on MATLAB/Simscape/Power Systems by using the equivalent circuit in Figure 3a in which leakage inductances of the HF transformer are assumed to be L_p = 3.2 μ H and L_s = 7.4 μ H, respectively, on the primary and secondary sides, and switching losses of all SiC power MOSFETs and Schottky diodes are neglected.

3.3.1. Optimum Transformer Turns-Ratio, *n*

The lowest and the highest maximum power point voltages for the multi-string PV system in Figure 2 are, respectively, $V_{mpp(min)} = 434 \text{ V}$ at $G = 50 \text{ W/m}^2$, $T_m = 70 \,^{\circ}\text{C}$, and $V_{mpp(max)} = 600 \text{ V}$ at $G = 1000 \text{ W/m}^2$, $T_m = 10 \,^{\circ}\text{C}$. Transformer turns-ratio is defined as $n = N_s/N_p$, where N_s and N_p are the number of series turns of the secondary and primary windings, respectively. The duty cycle, D, of the phase-shifted H-bridge converter is as defined in Equation (2).

$$D = t_{on}/(t_{on} + t_{off}) \tag{2}$$

where t_{on} is the power transfer period of phase-shifted H-bridge, and t_{off} is the sum of freewheeling and no-conduction periods. It is desirable to maintain the operation of H-bridge converter at relatively high D values over the entire operating range to keep corresponding peak values of SiC power semiconductor and transformer currents relatively low. The variation ranges of D for two different n values and extreme operating conditions are shown in Figure 10.

On the other hand, for an ideal MPPT converter, the lowest MPPT voltage, $V_{mpp(min)}$, over the entire operating range can be related to the chosen DC link voltage, $V_{dc} = 700$ V in terms of n and D as given in Equation (3). As an example, for D = 1.0 and $V_{mpp(min)} = 434$ V at G = 50 W/m² and $T_m = 70$ °C, n is found to be 1.61 from Equation (3). However, an n value lower than 1.61 can be chosen, since the total leakage inductance of the transformer provides boosting action in a practical MPPT converter.

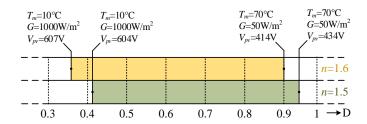


Figure 10. Variation range of duty cycle, D, for the practical MPPT converter as a function of n in between extreme operating conditions.

In the implemented MPPT converter, n = 1.52 is chosen for which D = 0.94 and $V_{mpp(min)} = 434$ V at G = 50 W/m² and $T_m = 70$ °C. This choice ensures power transfer even at the minimum G and maximum T_m conditions and provides a margin for better transient response.

$$V_{dc} = 700 \le V_{mpp(min)} \ n \ D \tag{3}$$

3.3.2. Choice of DC Link Capacitor of H-Bridge Converter

Operation modes of the MPPT converter in Figure 3 are as defined in Figure 11. The controllable section of the MPPT converter is the phase-shifted H-bridge converter. The stray inductance of the implemented DC-bus on PCB is estimated as $L_{stray} = 15.2$ nH. Two discrete metallized film capacitors are connected across the DC link, one for each leg of the H-bridge converter. Total DC link capacitance is denoted by C_i in Figures 3 and 11. Suppose now that initially S_1 and S_3 are conducting in power transfer mode in the positive half-cycle as shown in Figure 11a.

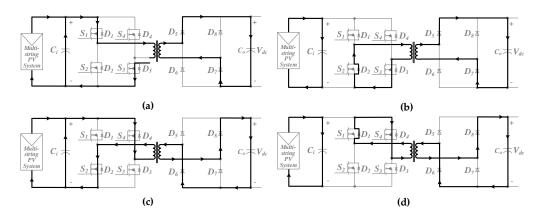


Figure 11. Operation modes of the MPPT converter for one complete cycle: (a) Mode 1: Power transfer in positive half-cycle; (b) Mode 2: Freewheeling in positive half-cycle; (c) Mode 3: Power transfer in negative half-cycle; and (d) Mode 4: Freewheeling in negative half-cycle.

When S_1 is turned off, current is commutated to D_2 which starts the freewheeling mode through S_3 and D_2 as shown in Figure 10b. The freewheeling mode is then followed by the OFF mode after the current decays to zero. For the negative half cycle, other diagonal switches S_2 and S_4 are turned on for power transfer mode which is followed by freewheeling mode through S_4 and D_1 , respectively, shown

in Figure 11c,d. Note that the converter is operated in the discontinuous conduction mode, owing to the absence of a lossy and bulky output filter inductor in the design.

Fall time of the SiC power MOSFET used in this research work is nearly 50 ns with increased gate resistance, R_g . During the commutation period, current closes its path mainly through C_i . The potential drop on L_{stray} is therefore $V_{stray} = L_{stray}$. ($\Delta I/\Delta t$) = 51 V for maximum possible device current of I_D = 200 A at f_{sw} = 20 kHz when G = 1000 W/m², T_m = 10 °C on the predefined geographical site. V_{stray} will then be superimposed on drain-to-source voltage, v_{DS} , of outgoing SiC power MOSFET. Since open-circuit voltage of the multi-string PV system is 800 V, peak value of v_{DS} never exceeds 850 V in the worst case which is safely below the v_{DS} rating of the chosen SiC power MOSFETs.

A high C_i value is always desirable for better system performance at the expense of higher size and hence cost. Simulation studies have shown that a C_i value in the range from 20//20 μ F to 40//40 μ F can be chosen in the implemented H-bridge converter. Effects of C_i on peak-to-peak ripple content of i_{pv} and v_{pv} , $i_{ci(rms)}$, and form factor of i_{cin} are shown in Figure 12 for standard test conditions ($G = 1000 \text{ W/m}^2$, $T_m = 25 \, ^{\circ}\text{C}$) and $f_{sw} = 20 \, \text{kHz}$. These curves show that:

- $i_{ci(rms)}$ and form factor of icin are not affected by C_i ; and
- Peak-to-peak ripple content of i_{pv} and v_{pv} reduces as C_i is increased. Lower peak-to-peak content on the PV side is always desirable, not only for potential drop on all series inductances but also for MPPT efficiency.

In view of these characteristics, C_i greater than or equal to 30//30 μ F seems to be suitable for the implemented H-bridge converter, provided that the commercially available metallized film capacitors can carry this rms current. In the implemented system $C_i = 30//30~\mu$ F is chosen which is bigger than the DC link capacitor recommended by the SiC power MOSFET manufacturer [73]. To justify that 30//30 μ F meets the entire operating range of the MPPT converter for the predefined geographical location and their commercial availability, characteristics in Figure 13 and manufacturer's data in Table 2 are given.

Table 2. Technical characteristics of some metallized film capacitors (1100 V DC at 70 °C) [74].

Capacity, μF	Code	I, A rms	ESR, mΩ
20	B32778T0206	13	11.9
30	B32778G0306	17.5	8.2
40	B32778G0406	21.5	6.2

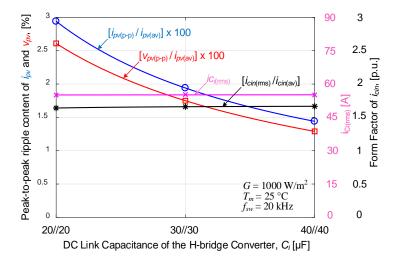


Figure 12. The variations in peak-to-peak ripple contents of i_{pv} and v_{pv} , $i_{ci(rms)}$, and form factor of i_{cin} against DC link capacitance of H-bridge converter for standard test conditions (these theoretical results were obtained using the dynamic model in Figure 5b; $f_{sw} = 20$ kHz assumed).

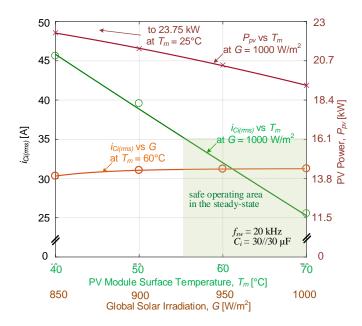


Figure 13. Effects of PV module surface temperature and global solar irradiation on $i_{ci(rms)}$ for 20 kHz switching frequency (these theoretical results were obtained from the dynamic model in Figure 5b; i_{ci} is defined in Figure 3a; $C_i = 30//30 \,\mu\text{F}$ is assumed; variations in power delivered by the multi-string PV system in Figure 2 against PV module surface temperature are also given on this figure).

3.3.3. Optimum Switching Frequency of H-bridge Converter

Variations in ripple contents of v_{pv} , i_{pv} , i_{Ci} , and i_{cin} against switching frequency, f_{sw} , obtained by simulation studies at standard test conditions for the chosen $C_i = 30//30 \,\mu\text{F}$ are as given in Figure 14.

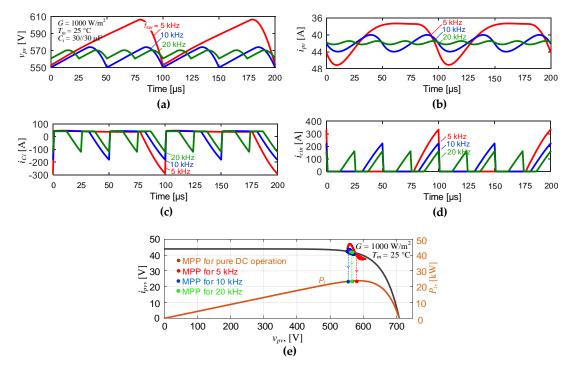


Figure 14. Variations in ripple content for different switching frequencies, f_{sw} : (a) PV panel voltage, v_{pv} ; (b) PV panel current, i_{pv} ; (c) input capacitor current, i_{Ci} ; (d) total current transferred to MPPT converter; i_{cin} , and (e) effects of f_{sw} on maximum power point of multi-string PV system in steady-state.

As can be understood from these waveforms, operation at higher switching frequency reduces ripple contents and hence rms values of all currents. Lower rms values for i_{cin} and i_{Ci} are better in the selection not only of SiC power MOSFET but also of DC link capacitor, C_i . These variations are quantified and presented in graphical form as a function of f_{sw} in Figure 15. It can be concluded from these characteristics that the phase-shifted MPPT converter should be switched at a frequency greater than or equal to 15 kHz. Figure 14e justifies this statement. Dynamic variations in MPPs arising from ripple content of i_{pv} are marked on i_{pv}/v_{pv} characteristic given in Figure 14e. Calculated mean MPPs are also marked on the same figure. The ideal case is pure DC operation. As f_{sw} is increased dynamic MPP curve converges to that of pure DC operation, e.g., MPP power for $f_{sw} = 20$ kHz is nearly the same with that of pure DC operation.

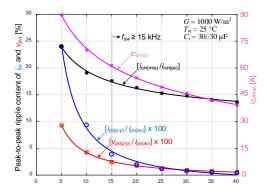


Figure 15. The variations in peak-to-peak ripple contents of i_{pv} and v_{pv} , $i_{Ci(rms)}$, and form factor of i_{cin} as a function of switching frequency (i_{pv} , v_{pv} , i_{Ci} , and i_{cin} are as defined in Figure 3a; these results were obtained by using the dynamic model in Figure 5b for the standard test conditions marked on the figure; DC link capacitance of the H-bridge converter in the MPPT converter is assumed to be $C_i = 30//30 \, \mu\text{F}$).

Thus far, in this subsection, only the factors for standard test conditions affecting the selection of f_{sw} have been considered. However, the entire operating range of the MPPT converter installed at the predefined geographical site gives more valuable information about the selection of f_{sw} . For this purpose, the variation range of duty ratio, D, for the H-bridge converter is calculated for different switching frequencies, and given in Figure 16. D should vary in a narrow range and at relatively high values to keep rms value of the semiconductor current, and hence its form factor at relatively low values. In view of these discussions, f_{sw} of the H-bridge converter should be at least 20 kHz.

In the selection of f_{sw} , the size of the HF transformer and the switching and conduction losses of H-bridge converter and conduction losses of Schottky diode rectifier should also be considered. Total semiconductor losses in the MPPT converter as a function of f_{sw} are given in Table 3. These losses exclude all wiring and cabling losses. It is seen in Table 3 that total power semiconductor losses in MPPT converter becomes minimum at $f_{sw} = 20$ kHz.

Table 3. Power semiconductor losses in MPPT converter against switching frequency (Operating Conditions: $P_{pv} = 25.1$ kW, G = 1000 W/m², $T_m = 10$ °C, $T_j = 80$ °C, $R_g = 10$ Ω).

H-Bridge Converter			Diode Bridge Rectifier		Total SiC MOSFET and SiC Diode Losses		
f _{sw} (kHz)	I _{peak} (A)	I _{rms} (A)	P _{cond} (W)	P _{sw} (W)	I _{ave} (A)	P _{cond} (W)	P _{total} (W)
5	380	84	452	82	17.3	111	645
10	280	72	332	140	17.3	111	583
20	200	60	230	232	17.3	111	573
30	160	54	187	313	17.3	111	611
40	140	50	160	388	17.4	111	659

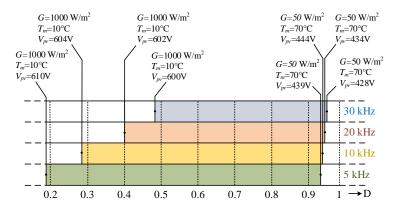


Figure 16. The variations in duty ratio, D of the H-bridge circuit in MPPT converter over the entire operating range for $f_{sw} = 5$, 10, 20, and 30 kHz, $V_{dc} = 700$ V, and $n = N_s/N_p = 1.52$.

3.3.4. HF Transformer Design

In this application, advanced types of ferrite, amorphous metal cobalt-base, amorphous metal iron-base, and nanocrystalline core materials can be used. Their recommended peak flux densities for operating frequency around 20 kHz are 0.3, 0.5, 1.3, and 1.0 T, respectively. The nanocrystalline core material has lower core loss than ferrite and much lower core loss than high flux density, amorphous metal iron-base material operating at the same peak flux density and frequency. On the other hand, although core loss density of the amorphous metal cobalt-base material is comparable to that of nanocrystalline material, it requires higher core volume resulting in higher total core loss and higher cost because of lower operating flux density. Nanocrystalline core material is therefore chosen in the design of the HF transformer with natural air cooling.

Rated values of the target transformer are specified as 23 kW, 20 kHz rated frequency, 700 V peak secondary voltage, and $n = N_s/N_p = 1.52$. SU102b nanocrystalline core is then used in the implementation of the HF transformer. Core loss, AC copper loss and total power loss of HF transformer against peak flux density are as given in Figure 17. Total power loss variation curve in Figure 17 shows that optimum design point can be chosen in between 0.25 T and 0.35 T. Design of the HF transformer is completed by choosing peak flux density as 0.3 T for minimum power dissipation at 20 kHz.

To test whether the design of MPPT converter is optimum, all power loss components excluding wiring and cabling losses are calculated and given in Figure 18 for three different operating frequencies and maximum PV power in the entire operating range of the MPPT converter installed at the predefined geographical site. Since $f_{sw} = 20$ kHz causes minimum power loss in the MPPT converter, the optimum design principles given in this subsection are justified.

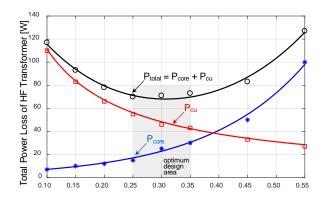


Figure 17. HF transformer power loss against peak flux density (23 kW, 700 V peak secondary voltage, $f_{sw} = 20$ kHz and n = 1.52 for SU102b nanocrystalline core).

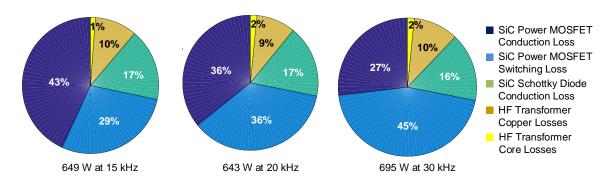


Figure 18. Power loss components of MPPT converter for different switching frequencies when $P_{vv} = 25.1$ kW. Numerical values are rounded.

3.3.5. Controller Design

The block diagram of the implemented DSP (TMS 320F28069) based controller is shown in Figure 3a. The controller is designed to fulfill the following tasks: (i) precharging the DC link capacitors, C_0 , of the HF link MPPT converter; (ii) MPPT operation; and (iii) overvoltage protection and drain-to-source voltage monitoring for shoot-through protection. For this purpose, DC link voltage, V_{dc} , and PV panel voltage and current, V_{pv} and I_{pv} , are input to the controller, at a sampling rate of 40 kHz/channel. Voltage transducers used are of Fully-Differential Isolation Amplifier (TI AMC-1100) type for noise immunity, and the current transducer is Hall-Effect type (LEM HASS 50-S).

When the sun rises, the PI controller in Figure 3a starts to operate by applying narrow pulses to limit the charging current of C_o to a safe value. Precharging period is less than 30 s, during which D does not exceed 0.15. Set value of the DC link voltage, $V_{dc(set)}$, is specified to be 700 V in the control software. Whenever V_{dc} reaches 700 V, the inverter control system is activated to start the transfer of power to the grid. Just after the inverter operation, the controller enables MPPT algorithm based on an adaptive version of Perturb and Observe method [75], which runs only once every 300 ms, and stops whenever the error in active power between any two consecutive iterations is less than 0.1%. The algorithm then starts afresh after 1 s. In each iteration, the magnitude of duty ratio perturbation, Δd , is only $\pm 0.25\%$ of the previous duty ratio, D. Sampled I_{pv} and V_{pv} data are averaged over a period of 25 ms (256 samples), not only to filter out the measurement noise but also for the use in overvoltage protection software. The inverter tends to keep V_{dc} constant, and overvoltage protection facility in the controller of MPPT converter does not allow a rise in V_{dc} more than 10% in the case of loss of control. Furthermore, v_{DS} monitoring is carried out by an analog chip within the SiC driver [76].

4. Field Test Results

4.1. HF Link MPPT Converter

Variations in ac components of v_{pv} and i_{pv} while the MPPT converter is supplied from the multi-string PV system in Figure 2 are given in Figure 19, for operation at two different switching frequencies. The following observations can be made about these waveforms:

- (i) Since the experimental results are the same with the theoretical ones based on the dynamic model of the PV array, the mathematical model and system design methodology can be successfully used in the design of the SiC power MOSFET-based HF link MPPT converter.
- (ii) v_{pv} and i_{pv} are nearly pure DC at f_{sw} = 20 kHz, i.e., only 6 V p-p ripple is superimposed on $V_{pv(av)}$ = 533 V and 0.3 A p-p ripple is superimposed on $I_{pv(av)}$ = 15.9 A. This justifies the optimum switching frequency of around 20 kHz, for the SiC HF link converter.

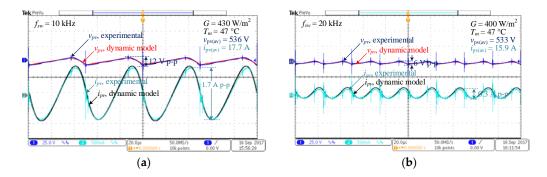


Figure 19. Variations in ac components of v_{pv} and i_{pv} while the MPPT converter supplied from multi-string PV system in Figure 2 is operating at two different switching frequencies in the steady-state: (a) $f_{sw} = 10$ kHz; and (b) $f_{sw} = 20$ kHz. (v_{pv} and i_{pv} are as defined in Figure 3a. Theoretical results have been obtained for the dynamic model in Figure 5b; v_{pv} and i_{pv} are recorded by using Tektronix MSO3034 oscilloscope, Tektronix P5205A high voltage differential probe, Tektronix TCP404XL current probe and Tektronix TCPA300 current probe amplifier.)

Drain-to-source voltage, v_{DS} , of SiC power MOSFET S_3 and the line current i_1 waveform of the H-bridge in Figure 3 are also recorded as shown in Figure 20. Positive half cycles of i_1 correspond to the drain current i_d waveform of S_3 . Note that all SiC power MOSFETs turn-on at zero-current owing to the ramp current waveform of the discontinuous conduction mode. At the turn-off, however, only S_3 and S_4 are switched at zero current at the end of the OFF period as illustrated in Figure 11b,d, due to the phase shifted operation. S_1 and S_2 , however, are switched off at the peak of the transformer primary current, i_1 . The glitches superimposed on v_{DS} waveform of S_3 in Figure 20 are attributed to the noise coupled to the oscilloscope voltage probe during switching-off of the other SiC power MOSFETs.

HF transformer voltage and current waveforms on both the primary and the secondary sides are as shown in Figure 21, at nearly full-load. Operation modes of the HF link converter, as defined in Figure 11 are marked on various segments of the recorded voltage and current waveforms in Figure 21. The voltage spikes at the turn-off of S_1 and S_2 (just at the beginning of freewheeling modes of S_3 - D_2 and S_4 - D_1) in Figure 21a are caused by the ringing between switches' output capacitances (C_{oss} = 880 pF) and the primary stray inductance of the current path between C_i and S_1 or S_2 (calculated from layout as $L_{stray1} \approx 27$ nH). The corresponding oscillation frequency is measured as 33 MHz, as expected. This effect is more pronounced at the secondary side waveforms in Figure 21b, owing to the resonance between the two outgoing Schottky diode output capacitances ($C_j \approx 1000$ pF each) and the secondary leakage inductance (L_s = 7.4 μ H), in series with the stray inductances ($L_{stray2} \approx 2.4 \mu$ H) between C_0 and the outgoing diodes, resulting in an oscillation frequency of 2.3 MHz. The slight voltage drops during freewheeling modes in Figure 21b are caused by L_{stray2} .

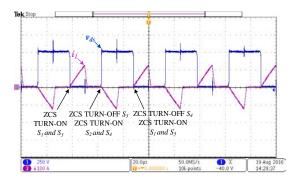


Figure 20. Drain-to-source voltage, v_{DS} , of SiC power MOSFET (S_3) and line current, i_1 , waveforms in the H-bridge circuit recorded by Tektronix MSO3034 oscilloscope, Tektronix P5205A high voltage differential probe and Rogowski CWTUM/3/B current probe ($f_{SW} = 20 \text{ kHz}$).

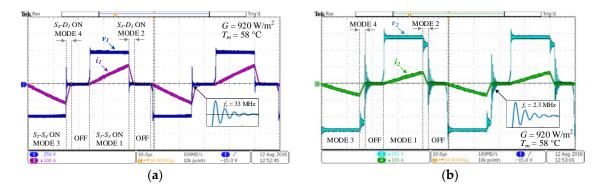


Figure 21. HF transformer voltage and current waveforms recorded by Tektronix MSO3034 oscilloscope, Tektronix P5205A high voltage differential probe and Rogowski CWTUM/3/B current probe (f_{sw} = 20 kHz, Test conditions are marked on the figure): (**a**) primary side; and (**b**) secondary side.

AC components of rectifier output current, i_{ro} , and the converter output current waveform, i_{dc} , in Figure 22 are recorded by a Rogowski current probe. Note that 72 A p-p rectifier output current ripple at full-load is filtered down to 12 A p-p by the low ESR DC link capacitor C_o .

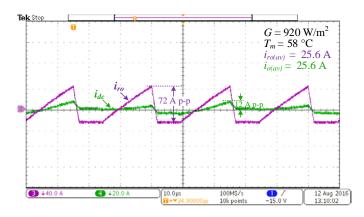


Figure 22. AC components of rectifier output current, i_{ro} , and the converter output current waveform, i_{dc} , recorded by Rogowski CWTUM/3/B current probe (average values of i_{ro} and i_{dc} and test conditions are marked on the figure; $f_{sw} = 20 \text{ kHz}$).

4.2. Voltage Source Inverter

Since the three-phase two-level VSI is built by using a full SiC six-pack module, only the drain-to-source voltages v_{DS} and unfiltered line currents i_a , i_b , and i_c can be recorded. Figure 23 shows the circuit diagram of first leg of the inverter and the associated unfiltered line current, i_a . To investigate effects of dead band on the turn-off performance of SiC power MOSFETs, v_{DS4} and i_a are recorded around the zero-crossing point of the unfiltered line-a current waveform for various dead times, as shown in Figure 24. These waveforms are as shown in Figure 24a when dead band is adjusted to 400 ns. Since current is very low, C_{oss4} and C_{oss1} are, respectively, charging and discharging slowly. When M_1 is turned on at the end of the dead band period, C_{oss4} is not charged yet to V_{dc} = 700 V and the C_{oss1} is not discharged entirely. The residual voltage on C_{oss1} will then be superimposed on DC link voltage which appears across the drain-source terminals of S_4 (v_{DS4}). A shorter dead band causes a larger overshoot on v_{DS4} waveform. This phenomenon does not occur around the peak value of unfiltered line-a current. This is because C_{oss4} and C_{oss1} , respectively, charges and discharges more rapidly since the current is high.

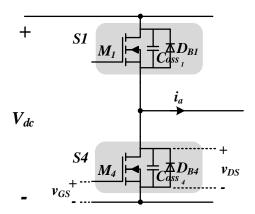


Figure 23. First leg of PV inverter and supply line-a (S:SiC power MOSFET, M:MOSFET part, C_{oss} : output capacitance, DB: body diode, and i_a : unfiltered line-a current).

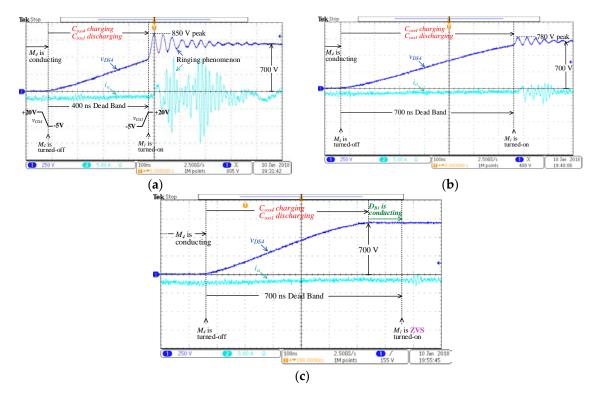


Figure 24. Effects of dead band on turn-off behavior of S_4 around zero crossing of the unfiltered line current (symbols are as defined in Figure 22 and v_{DS} and i_a are recorded by Tektronix MSO3034 oscilloscope, Tektronix P5205A high voltage differential probe, Tektronix TCP404XL current probe, Tektronix TCPA300 current probe amplifier): (a) 400 ns dead band; (b) 700 ns dead band; and (c) 700 ns dead band with ZVS turn-on of M_1 .

On the other hand, ringing phenomenon is observed on v_{DS4} when S_1 is turned on due to the damped high frequency oscillation between the stray inductance of DC bus and C_{oss1} . In general, shorter dead time reduces low order harmonic distortion in line current waveforms at the expense of higher switching loss at turn-on and high frequency harmonic component. As can be seen in Figure 24b, a longer dead time (700 ns) reduces peak value of v_{DS4} and alleviates ringing phenomenon. At a current level slightly higher than that of Figure 24a,b, 700 ns dead time eliminates entirely ringing phenomenon and leads to ZVS turn-on of M_1 as shown in Figure 24c at the expense of higher low order harmonic distortion. In view of these considerations, 400 ns dead time is used in the implementation.

To investigate the transient performance of the VSI control system, multi-string PV system is suddenly disconnected from the input of the MPPT converter while the PV supply is delivering nearly 11 kW to the grid. The recorded filtered line current and the DC link voltage waveforms are as shown in Figure 25. Just after disconnection V_{dc} makes nearly 20% undershoot and then settles down to 98% of its rated value in nearly 480 ms. It is worth noting that, after reaching minimum V_{dc} , the voltage source converter starts to operate in rectification mode to allow power transfer from the grid to the DC link, thus maintaining V_{dc} at 700 V. Transient response is affected primarily by the size of the DC link capacitor and secondarily the LCL filter. V_{dc} in Figure 25 would decay more rapidly in the case of a smaller C_0 , thus increasing undershoot in V_{dc} . To compensate for this phenomenon a larger size LCL filter could be used. A larger LCL filter would allow to increase the control range and hence the voltage source converter could settle down to the new operation state much more rapidly.

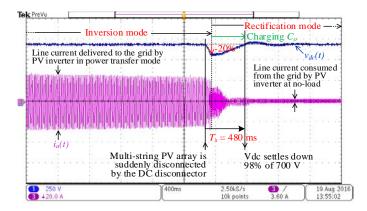


Figure 25. $v_{dc(t)}$ and $i_{a(t)}$ waveforms recorded by Tektronix MSO3034 oscilloscope, Tektronix P5205A high voltage differential probe Tektronix TCP404XL current probe and Tektronix TCPA300 current probe amplifier when the multi-string PV array is suddenly disconnected from MPPT converter.

4.3. Harmonic Distortion

Snapshots of the grid-side electrical quantities are given in Figure 26 for operation at full-load (Figure 26, left) and half-load (Figure 26, side). Figure 26a gives the three-phase voltages and line current waveforms, and Figure 26b the associated harmonic current contents according IEC61000-4-7:2002 harmonic measurement method [77], including both the line harmonics and the interharmonics. The rms quantities and output powers are recorded as shown in Figure 26c. The following observations can be made about these waveforms:

- The inverter operates connected to the 50-Hz AC grid with a total harmonic distortion, THDv $\approx 1.4\%$ for the line-to-line voltages, and dominant 5th and 7th harmonics. The current THDi is recorded to be 3.8% at full-load, and 4.3% at half-load, with dominant 5th and 7th harmonics as in the AC grid. These current THD values correspond to current TDD values, respectively, of 3.4% and 1.9% by taking 25 kVA as the apparent power rating of the VSI.
- The resulting individual line current harmonics obtained experimentally are found to be within the recommended limits by the IEEE Std.-519-2014 [78] for all supply conditions, as can be seen from Figures 26b and 27 for a harmonic spectrum up to the 50th.
- The inverter operates successfully at unity pf, (pf \approx 0.999 recorded), under both the full-load and the half-load conditions, according to the preset value, $I_{q(set)} = 0$.

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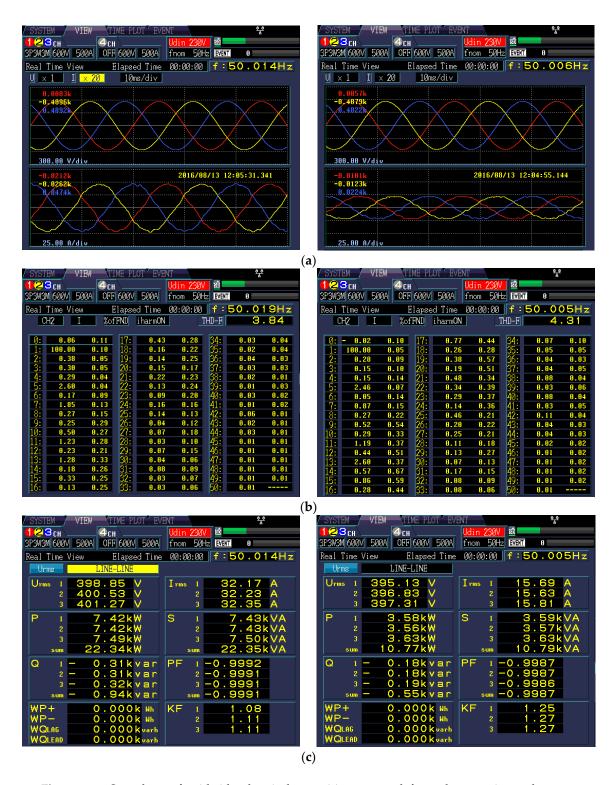


Figure 26. Snapshots of grid-side electrical quantities captured from the experimental set-up in Figure 1b by Hioki Power Analyzer PW3198 at $P_o = 22$ kW (left) and $P_o = 11$ kW (right): (a) line-to-line voltage and line current waveforms; (b) harmonic content of line current waveforms; and (c) output powers.

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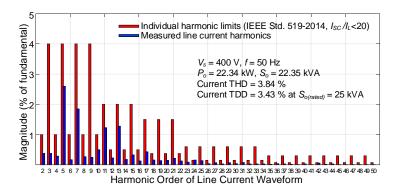


Figure 27. Sample harmonic spectra for the line current waveform injected by the inverter to the utility grid (deduced from the records of Hioki Power Analyzer PW3198 in Figure 26b).

In this research work, the LCL filter is optimized to yield minimum filter size and hence cost. To illustrate the effects of LCL filter size on the harmonic distortion of line current waveforms, L_g is increased from 50 μ H to 1.5 mH, as preferred by several researchers in their implementations, and then the harmonic distortion record is repeated at 10 kVA. These records are given in Figure 28. THD and TDD values of the line current waveforms are 2.26% and 0.9%, respectively. It is seen that a larger size and hence more dissipative and costly LCL filter yields much lower harmonic distortion in line current waveforms.



Figure 28. Snapshots of grid-side electrical quantities captured from the experimental set-up in Figure 1b by Hioki Power Analyzer PW3198 at $P_o = 10$ kW for $L_g = 1.5$ mH: (a) line-to-line voltage and line current waveforms; and (b) harmonic content of line current waveforms.

4.4. Efficiency

Efficiencies of HF link MPPT converter, VSI, and the overall grid-connected PV supply are obtained separately by field measurements for different operating conditions. Experimental results are given in comparison with theoretical values. For efficiency calculations, power components P_i , $P_{o(MPPT)}$, and P_o are as defined in Figure 29. For different operating conditions, $P_i = v_{pv(av)}.i_{pv(av)}$ and $P_{o(MPPT)} = v_{dc(av)}.i_{dc(av)}$ are calculated from measured $v_{pv(av)}$, $i_{pv(av)}$, $v_{dc(av)}$, and $i_{dc(av)}$ data as described in the caption of Figure 29. A sample set of $v_{pv(av)}$, $i_{pv(av)}$, $v_{dc(av)}$, and $i_{dc(av)}$ waveforms is given in Figure 30. Experimental efficiency values for the MPPT converter calculated from field data for different operating conditions are given in Table 4. For the corresponding insolation levels and module temperatures, the theoretical efficiency values are also calculated by using the MPPT converter model including the dynamic model of the multi-string PV system and running it on MATLAB Simulink at $f_{sw} = 20$ kHz. These theoretical values are also marked in Table 4. The following conclusions can be drawn from these results:

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- (i) Maximum efficiency occurs at nearly half-load.
- (ii) Full-load efficiency (97.3%) is only 0.5% lower than the maximum efficiency (97.7%).

(iii) Experimental values are slightly lower than corresponding theoretical values (discrepancies, $\delta \eta \le 4\%$ at low power levels and $\delta \eta < 1\%$ at high powers).

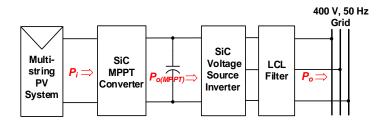


Figure 29. Definition of power components for efficiency calculations. P_i is calculated from the measured $v_{pv(av)}$ and $i_{pv(av)}$ data. $P_{o(MPPT)}$ is calculated from the measured $v_{dc(av)}$ and $i_{dc(av)}$ data. Measuring instruments are Tektronix MSO3034 oscilloscope together with its moving average filters, Tektronix P5205A high voltage differential probe, Tektronix TCP404XL current probe, Tektronix TCPA300 current probe amplifier, and Fluke 80i-110s current probe for i_{dc} . P_o is measured by Hioki Power Analyzer PW3198. Instantaneous values v_{pv} , i_{pv} , v_{dc} and i_{dc} are as defined in Figure 3 before averaging for steady-state operation.

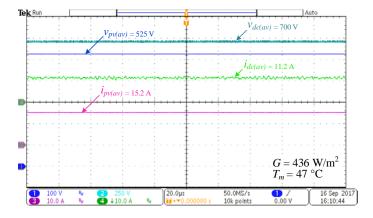


Figure 30. A sample set of $v_{pv(av)}$, $i_{pv(av)}$, $v_{dc(av)}$ and $i_{dc(av)}$ waveforms recorded at $G = 436 \text{ W/m}^2$, and $T_m = 47 \,^{\circ}\text{C}$.

Experimental efficiency values for the SiC VSI calculated from field data for different $P_{o(MPPT)}$ values are given in Table 5. Theoretical values of P_o are calculated by subtracting all inverter losses from experimental values of $P_{o(MPPT)}$. For the SiC VSI, computer simulations are carried out using the Wolfspeed SpeedFit design simulation software [72] to calculate SiC MOSFET losses, and Magnetics Inductor Design Tool [79] to determine the LCL filter losses. The following conclusions can be drawn from the results in Table 5:

- (i) Maximum efficiency (98.6%) occurs nearly at 40% of full 22.3 kW-load.
- (ii) Efficiency is 98.1% at 88% of full kW-load.
- (iii) Experimental values are slightly lower than corresponding theoretical values (discrepancies, $\delta \eta \le 2\%$ at low power levels and $\delta \eta < 1\%$ at high powers).

The variations in efficiency of the all-SiC PV supply are calculated from field data and given in Figure 31 as a function of P_o . Maximum efficiency is observed to be 97%. Full-load efficiency is estimated to be slightly higher than 96%. At very low power levels such as 10% of the full-load, the overall efficiency is around 92%. These efficiency values are comparable with those of new

generation PV supplies containing boost type MPPT converters and hybrid IGBT based inverters of the same power ratings and supplied from the existing multi-string PV system in Figure 2.

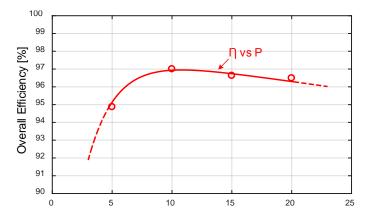


Figure 31. Efficiency of all SiC grid-connected PV supply against output power, $\eta = [P_o/P_i] \times 100$ (experimental values of P_o and P_i are obtained as described in the caption of Figure 29).

In the case where the multi-string PV system is initially not available and the types of the modules are not prespecified, the optimum multi-string PV system configuration and its technical characteristics will be a design issue for the overall grid-connected PV supply. The structure and technical characteristics of the multi-string PV system mainly affect the efficiency of the MPPT converter and hence efficiency of the overall system. To illustrate this fact, simulation studies for two different cases which employ 100 CSUN250-72M modules were carried out. In Case 1, 100 modules are connected to give 4×25 multi-string PV system to illustrate the effects of high operating voltage and low current on the efficiency of MPPT converter. In Case 2, the same modules are connected to give 5×20 multi-string PV system with lower operating voltage and higher current. The simulation results are as given in Figure 32. As can be understood from Figure 32, under standard test conditions, Case 1 gives 99% converter efficiency at nearly half-load and, when it is combined with inverter efficiency, the maximum efficiency of the overall system may reach 98.1%. This is because the operation of the MPPT converter with HF link in Figure 3 at a lower PV current, i_{pv} , reduces conduction loss components remarkably, thus improving the converter efficiency.

Test Condition *	on * P_i , kW		$P_{o(MPP)}$	_{T)} , kW	Efficiency, $\eta = [P_{o(MPPT)}/P_i]$ 100, %	
G and T _m	Experimental *	Theoretical †	Experimental *	Theoretical °	Experimental	Theoretical
$G = 70 \text{ W/m}^2$ $T_m = 32 \text{ °C}$	1.66	1.60	1.49	1.55	89.76	93.47
$G = 150 \text{ W/m}^2$ $T_m = 35 ^{\circ}\text{C}$	3.28	3.14	3.08	3.13	93.90	95.55
$G = 250 \text{ W/m}^2$ $T_m = 38 ^{\circ}\text{C}$	4.51	5.19	4.32	5.01	95.78	96.69
$G = 370 \text{ W/m}^2$ $T_m = 40 ^{\circ}\text{C}$	8.91	8.23	8.70	8.04	97.64	97.69
$G = 490 \text{ W/m}^2$ $T_m = 49 ^{\circ}\text{C}$	10.61	10.21	10.37	10.02	97.73	98.20
$G = 730 \text{ W/m}^2$ $T_m = 57 ^{\circ}\text{C}$	15.52	15.42	15.14	15.04	97.55	97.56

Table 4. Comparison of experimental and theoretical efficiency values of MPPT converter.

19.59

20.05

97.26

97.28

20.61

 $G = 980 \text{ W/m}^2$

 $T_m = 60$ °C

20.14

^{*} Experimental values of P_i and $P_{o(MPPT)}$ are determined as defined in Figure 29 for different test conditions.

[†] Theoretical values of P_i are calculated for the same test conditions by using the dynamic model in Figure 5b.

 $^{^{\}circ}$ Theoretical values of $P_{o(MPPT)}$ are calculated by adding all MPPT converter losses to theoretical values of P_i .

$P_{o(MPPT)}$, kW	P _o , kW		Efficiency, $\eta = [P_o/P_{o(MPPT)}]$ 100, %		
Experimental *	Experimental *	Theoretical †	Experimental	Theoretical	
3.08	2.99	3.05	97.05	99.00	
4.31	4.21	4.27	97.54	99.05	
8.69	8.57	8.61	98.55	99.10	
10.37	10.21	10.27	98.46	99.10	
15.13	14.88	14.98	98.32	99.05	
19.58	19.21	19.38	98.09	99.00	

Table 5. Comparison of experimental and theoretical efficiency values of SiC inverter.

[†] Theoretical values of P_o are calculated by subtracting all inverter losses from experimental values of $P_{o(MPPT)}$.

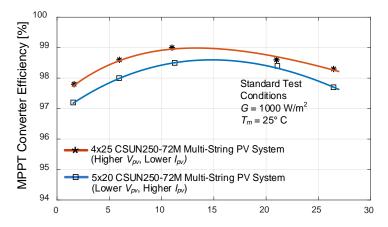


Figure 32. Effects of the configuration of multi-string PV system on the efficiency of MPPT converter with HF link in Figure 3 (Simulation results).

5. Conclusions

A system design methodology for an all SiC grid-connected PV supply with HF link MPPT converter has been proposed and a prototype of 25 kVA converter operating at 20 kHz has been implemented for verification. Owing to the very high dv/dt (>10 kV/ μ s) ratings of SiC power semiconductors, common-mode EMI is more pronounced in SiC based non-isolated converters. In this work, galvanic isolation of the proposed MPPT converter overcomes the common-mode EMI problem, thus enabling the grid connection using a simple and reliable three-phase, two-level inverter. In the design of the HF link MPPT converter operating at 20 kHz, a dynamic model of the multi-string PV system, parameters of which are obtained from the field test results, is used. More realistic MPPT converter parameters are shown to be obtained in the paper by using the dynamic PV model in the design procedure in comparison with the well-known static PV models.

The optimum switching frequency of the 25 kVA three-phase two-level inverter is determined as 20 kHz in the design procedure in view of inverter losses. The resulting 25 kVA, 20 kHz SiC VSI has 98.5% maximum efficiency which is slightly higher than or comparable with those of new-generation IGBT (Si IGBT + antiparallel SiC Schottky Diode) based counterparts for the existing multi-string PV system in Figure 2. This relatively high switching frequency not only reduces the size of the passive components, such as the LCL filter and the HF transformer but also the size of the cooling aggregates. LCL filter of the VSI, which is optimized by considering stability concerns of the controller in the design, provides nearly 100 dB attenuation at 20 kHz and its size is at least ten times smaller than those of LCL filter designs reported in the literature, even for lower size converters. TDD of the grid-connected VSI is measured to be 3.9% at nearly full-load and its individual current harmonics up to 50th conform with IEC Std. 61000-4-7:2002 even for the weakest grid. A higher grid-side inductance

^{*} Experimental values of $P_{o(MPPT)}$ and P_o are obtained as defined in Figure 29 for different operating conditions.

(L_g = 1.5 mH) of the LCL filter lowers the current THDs considerably, which is measured to be 2.3% at nearly half-load.

The resulting SiC MPPT converter operating at 20 kHz and supplied from the existing 5×19 multi-string PV system in Figure 2 has 98% measured maximum efficiency, which is comparable with IGBT based and lower than SiC based boost type MPPT converters. Power densities are calculated as nearly 1.8 kW/lt and 1.6 kW/lt for forced air-cooled SiC MPPT converter and SiC grid-connected VSI, respectively. These figures are higher than those of forced air-cooled new-generation IGBT based converters and much higher than those of natural air-cooled new-generation IGBT based converters.

Author Contributions: M.E. and I.Ç. conceived the presented idea. M.C. and M.E. developed and implemented the SiC inverter. S.Ö. and I.Ç. developed and implemented the SiC MPPT converter. All authors discussed the results and contributed to the final manuscript.

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